

Pin	Symbol		Function
1	GND	-	Logic ground
2	IN	I	Input, activates the power switch in case of logical high signal
3	V _{bb}	+	Positive power supply voltage, the tab is shorted to this pin
4	ST	S	Diagnostic feedback, low on failure
5	OUT (Load, L)	O	Output to the load

Maximum Ratings at $T_j = 25\text{ °C}$ unless otherwise specified

Parameter	Symbol	Values	Unit
Supply voltage (overvoltage protection see page 3)	V_{bb}	65	V
Load dump protection ²⁾ $V_{LoadDump} = U_A + V_s$, $U_A = 13.5\text{ V}$ $R_I^3 = 2\text{ }\Omega$, $R_L = 6.6\text{ }\Omega$, $t_d = 400\text{ ms}$, IN= low or high	$V_{Load\ dump}^4)$	100	V
Load current (Short circuit current, see page 4)	I_L	self-limited	A
Junction temperature	T_j	+150	°C
Operating temperature range	T_a	-30 ... +85	
Storage temperature range	T_{stg}	-40 ... +105	
Power dissipation (DC), $T_C \leq 25\text{ °C}$	P_{tot}	50	W
Inductive load switch-off energy dissipation, single pulse $V_{bb} = 12\text{ V}$, $T_{j,start} = 150\text{ °C}$, $T_C = 150\text{ °C}$ const. $I_L = 1.8\text{ A}$, $Z_L = 2.3\text{ H}$, $0\text{ }\Omega$:	E_{AS}	4.5	J
Electrostatic discharge capability (ESD) (Human Body Model) IN: all other pins: acc. MIL-STD883D, method 3015.7 and ESD assn. std. S5.1-1993	V_{ESD}	1 2	kV
Input voltage (DC)	V_{IN}	-0.5 ... +6	V
Current through input pin (DC)	I_{IN}	± 5.0	mA
Current through status pin (DC)	I_{ST}	± 5.0	
see internal circuit diagrams page 6			

Thermal Characteristics

Parameter and Conditions	Symbol	Values			Unit
		min	typ	max	
Thermal resistance chip - case:	R_{thJC}	--	--	2.5	K/W
junction - ambient (free air):	R_{thJA}	--	--	75	

²⁾ Supply voltages higher than $V_{bb(AZ)}$ require an external current limit for the GND and status pins, e.g. with a $150\text{ }\Omega$ resistor in the GND connection and a $15\text{ k}\Omega$ resistor in series with the status pin. A resistor for the protection of the input is integrated.

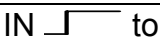
³⁾ R_I = internal resistance of the load dump test pulse generator

⁴⁾ $V_{Load\ dump}$ is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839

Electrical Characteristics

Parameter and Conditions at $T_j = 25^\circ\text{C}$, $V_{bb} = 12\text{ V}$ unless otherwise specified	Symbol	Values			Unit
		min	typ	max	

Load Switching Capabilities and Characteristics

On-state resistance (pin 3 to 5) $I_L = 1.6\text{ A}$ $T_j = 25^\circ\text{C}$: $T_j = 150^\circ\text{C}$:	R_{ON}	--	190 390	220 440	mΩ
Nominal load current, ISO Norm (pin 3 to 5) $V_{ON} = 0.5\text{ V}$, $T_C = 85^\circ\text{C}$	$I_{L(ISO)}$	1.6	1.8	--	A
Output current (pin 5) while GND disconnected or GND pulled up, $V_{bb}=30\text{ V}$, $V_{IN}=0$, see diagram page 7, $T_j = -40\dots+150^\circ\text{C}$	$I_{L(GNDhigh)}$	--	--	1	mA
Turn-on time IN  to 90% V_{OUT} :	t_{on}	12	--	125	μs
Turn-off time IN  to 10% V_{OUT} : $R_L = 12\text{ Ω}$, $T_j = -40\dots+150^\circ\text{C}$	t_{off}	5	--	85	μs
Slew rate on 10 to 30% V_{OUT} , $R_L = 12\text{ Ω}$, $T_j = -40\dots+150^\circ\text{C}$	dV/dt_{on}	--	--	3	V/μs
Slew rate off 70 to 40% V_{OUT} , $R_L = 12\text{ Ω}$, $T_j = -40\dots+150^\circ\text{C}$	$-dV/dt_{off}$	--	--	6	V/μs

Operating Parameters

Operating voltage ⁵⁾ $T_j = -40\dots+150^\circ\text{C}$:	$V_{bb(on)}$	4.7	--	42	V
Undervoltage shutdown $T_j = 25^\circ\text{C}$: $T_j = -40\dots+150^\circ\text{C}$:	$V_{bb(under)}$	2.9 2.7	--	4.5 4.7	V
Undervoltage restart $T_j = -40\dots+150^\circ\text{C}$:	$V_{bb(u\text{ rst})}$	--	--	4.9	V
Undervoltage restart of charge pump see diagram page 13	$V_{bb(ucp)}$	--	5.6	6.0	V
Undervoltage hysteresis $\Delta V_{bb(under)} = V_{bb(u\text{ rst})} - V_{bb(under)}$	$\Delta V_{bb(under)}$	--	0.1	--	V
Overvoltage shutdown $T_j = -40\dots+150^\circ\text{C}$:	$V_{bb(over)}$	42	--	52	V
Overvoltage restart $T_j = -40\dots+150^\circ\text{C}$:	$V_{bb(o\text{ rst})}$	40	--	--	V
Overvoltage hysteresis $T_j = -40\dots+150^\circ\text{C}$:	$\Delta V_{bb(over)}$	--	0.1	--	V
Overvoltage protection ⁶⁾ $I_{bb}=4\text{ mA}$ $T_j = -40\dots+150^\circ\text{C}$:	$V_{bb(AZ)}$	65	70	--	V
Standby current (pin 3) $V_{IN}=0$ $T_j = -40\dots+25^\circ\text{C}$: $T_j = 150^\circ\text{C}$:	$I_{bb(off)}$	--	10 18	15 25	μA
Leakage output current (included in $I_{bb(off)}$) $V_{IN}=0$	$I_{L(off)}$	--	--	20	μA
Operating current (Pin 1) ⁷⁾ , $V_{IN}=5\text{ V}$, $T_j = -40\dots+150^\circ\text{C}$	I_{GND}	--	1	2.1	mA

⁵⁾ At supply voltage increase up to $V_{bb} = 5.6\text{ V}$ typ without charge pump, $V_{OUT} \approx V_{bb} - 2\text{ V}$

⁶⁾ Measured without load. See also $V_{ON(CL)}$ in table of protection functions and circuit diagram page 7.

Parameter and Conditions at $T_j = 25^\circ\text{C}$, $V_{bb} = 12\text{ V}$ unless otherwise specified	Symbol	Values			Unit
		min	typ	max	
Protection Functions ⁸⁾					
Initial peak short circuit current limit (pin 3 to 5) ⁹⁾ , (max 450 μs if $V_{ON} > V_{ON(SC)}$) $T_j = -40^\circ\text{C}$: $T_j = 25^\circ\text{C}$: $T_j = +150^\circ\text{C}$:	$I_{L(SCp)}$	9 -- 4	-- 12 --	23 -- 15	A
Repetitive overload shutdown current limit $V_{ON} = 8\text{ V}$, $T_j = T_{jt}$ (see timing diagrams, page 12)	$I_{L(SCr)}$	--	5	--	A
Short circuit shutdown delay after input pos. slope $V_{ON} > V_{ON(SC)}$, min value valid only, if input "low" time exceeds 60 μs $T_j = -40..+150^\circ\text{C}$:	$t_{d(SC)}$	--	--	450	μs
Output clamp (inductive load switch off) at $V_{OUT} = V_{bb} - V_{ON(CL)}$ $I_L = 40\text{ mA}$, $T_j = -40..+150^\circ\text{C}$: $I_L = 1\text{ A}$, $T_j = -40..+150^\circ\text{C}$:	$V_{ON(CL)}$	61 --	68 --	73 75	V
Short circuit shutdown detection voltage (pin 3 to 5)	$V_{ON(SC)}$	--	8.5	--	V
Thermal overload trip temperature	T_{jt}	150	--	--	$^\circ\text{C}$
Thermal hysteresis	ΔT_{jt}	--	10	--	K
Reverse battery (pin 3 to 1) ¹⁰⁾	$-V_{bb}$	--	--	32	V

Diagnostic Characteristics

Open load detection current (on-condition) $T_j = -40..150^\circ\text{C}$:	$I_L(OL)$	2	--	150	mA
--	-----------	---	----	-----	----

⁷⁾ Add I_{ST} , if $I_{ST} > 0$, add I_{IN} , if $V_{IN} > 5.5\text{ V}$

⁸⁾ Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

⁹⁾ Short circuit current limit for max. duration of $t_{d(SC)}$ max=450 μs , prior to shutdown

¹⁰⁾ Requires 150 Ω resistor in GND connection. The reverse load current through the intrinsic drain-source diode has to be limited by the connected load. Note that the power dissipation is higher compared to normal operating conditions due to the voltage drop across the intrinsic drain-source diode. The temperature protection is not active during reverse current operation! Input and Status currents have to be limited (see max. ratings page 2 and circuit page 7).

Parameter and Conditions at $T_j = 25\text{ }^{\circ}\text{C}$, $V_{bb} = 12\text{ V}$ unless otherwise specified	Symbol	Values			Unit
		min	typ	max	
Input and Status Feedback ¹¹⁾					
Input turn-on threshold voltage $\nearrow T_j = -40..+150^{\circ}\text{C}$:	$V_{\text{IN}(\text{T}+)}$	1.5	--	2.4	V
Input turn-off threshold voltage $\searrow T_j = -40..+150^{\circ}\text{C}$:	$V_{\text{IN}(\text{T}-)}$	1.0	--	--	V
Input threshold hysteresis	$\Delta V_{\text{IN}(\text{T})}$	--	0.5	--	V
Off state input current (pin 2), $V_{\text{IN}} = 0.4\text{ V}$	$I_{\text{IN}(\text{off})}$	1	--	30	μA
On state input current (pin 2), $V_{\text{IN}} = 5\text{ V}$	$I_{\text{IN}(\text{on})}$	10	25	70	μA
Status invalid after positive input slope (short circuit) $T_j = -40 \dots +150^{\circ}\text{C}$:	$t_{\text{d}(\text{ST SC})}$	--	--	450	μs
Status invalid after positive input slope (open load) $T_j = -40 \dots +150^{\circ}\text{C}$:	$t_{\text{d}(\text{ST})}$	300	--	1400	μs
Status output (open drain)					
Zener limit voltage $T_j = -40...+150^{\circ}\text{C}$, $I_{\text{ST}} = +50\text{ }\mu\text{A}$:	$V_{\text{ST}(\text{high})}$	5.0	6	--	V
ST low voltage $T_j = -40...+150^{\circ}\text{C}$, $I_{\text{ST}} = +1.6\text{ mA}$:	$V_{\text{ST}(\text{low})}$	--	--	0.4	

¹¹⁾ If a ground resistor R_{GND} is used, add the voltage drop across this resistor.

Truth Table

	Input-level	Output level	Status 410 E2
Normal operation	L	L	H
	H	H	H
Open load	L	¹²⁾	H
	H	H	L
Short circuit to GND	L	L	H
	H	L	L
Short circuit to V_{bb}	L	H	H
	H	H	H (L ¹³⁾)
Overtemperature	L	L	L
	H	L	L
Undervoltage	L	L	H
	H	L	H
Overvoltage	L	L	H
	H	L	H

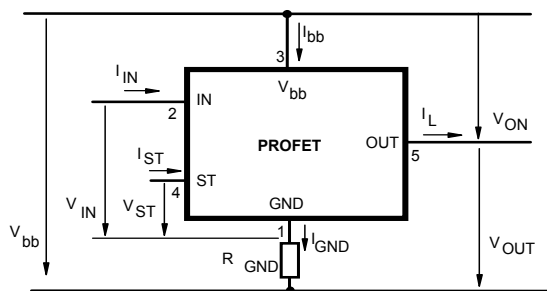
L = "Low" Level
H = "High" Level

X = don't care

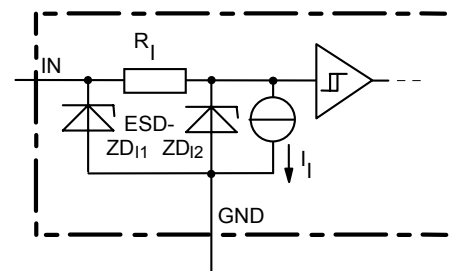
Z = high impedance, potential depends on external circuit

Status signal after the time delay shown in the diagrams (see fig 5. page 13)

Terms



Input circuit (ESD protection)

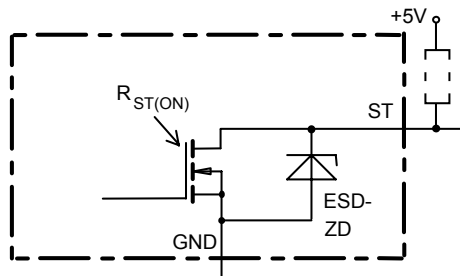


ZD11 6 V typ., ESD zener diodes are not to be used as voltage clamp at DC conditions. Operation in this mode may result in a drift of the zener voltage (increase of up to 1 V).

¹²⁾ Power Transistor off, high impedance.

¹³⁾ Low resistance short V_{bb} to output may be detected in ON-state by the no-load-detection

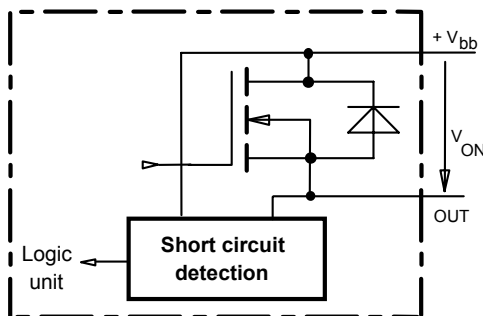
Status output



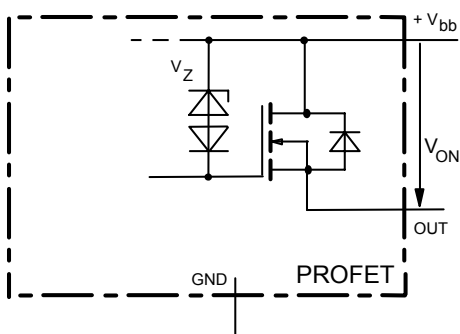
ESD-Zener diode: 6 V typ., max 5 mA;
 $R_{ST(ON)} < 250 \Omega$ at 1.6 mA, ESD zener diodes are not to be used as voltage clamp at DC conditions.
 Operation in this mode may result in a drift of the zener voltage (increase of up to 1 V).

Short circuit detection

Fault Condition: $V_{ON} > 8.5 \text{ V typ.}$; IN high

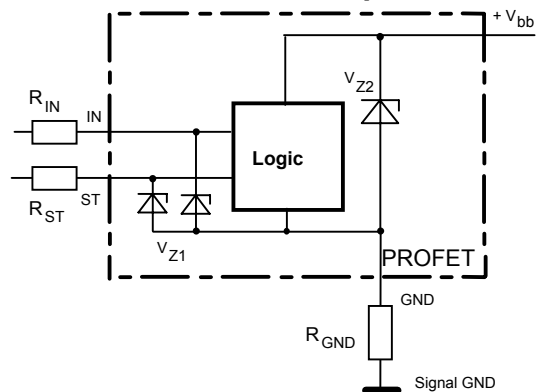


Inductive and overvoltage output clamp



V_{ON} clamped to 68 V typ.

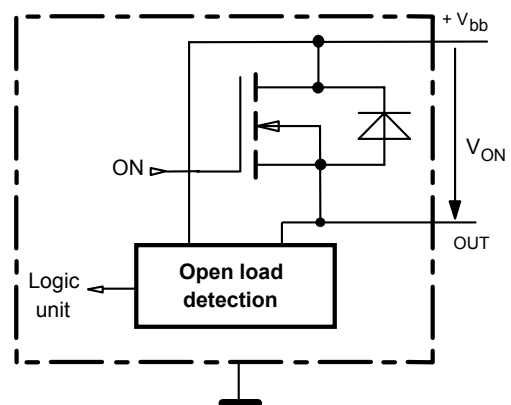
Overvolt. and reverse batt. protection



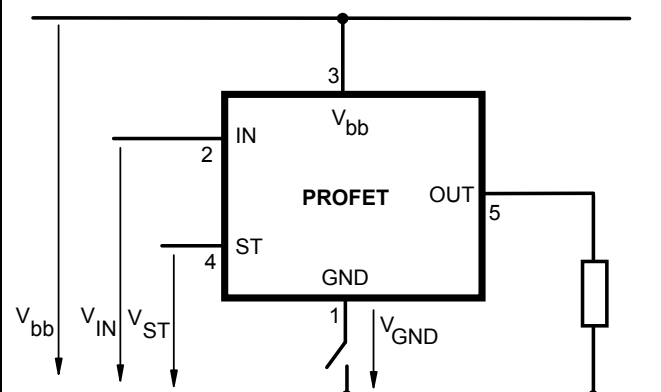
$V_{Z1} = 6.2 \text{ V typ.}$, $V_{Z2} = 70 \text{ V typ.}$, $R_{GND} = 150 \Omega$, R_{IN} , $R_{ST} = 15 \text{ k}\Omega$

Open-load detection

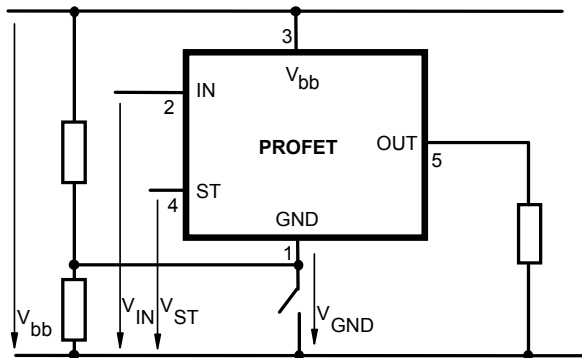
ON-state diagnostic condition: $V_{ON} < R_{ON} * I_{L(OL)}$; IN high



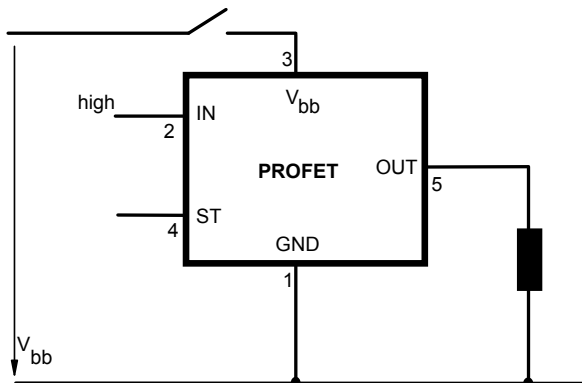
GND disconnect



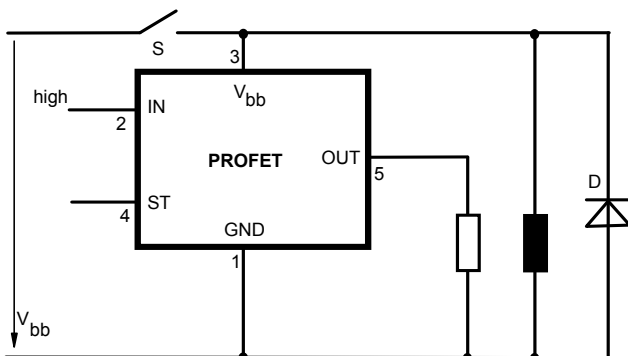
Any kind of load. In case of Input=high is $V_{OUT} \approx V_{IN} - V_{IN(T+)}$.
 Due to $V_{GND} > 0$, no $V_{ST} = \text{low signal}$ available.

GND disconnect with GND pull up


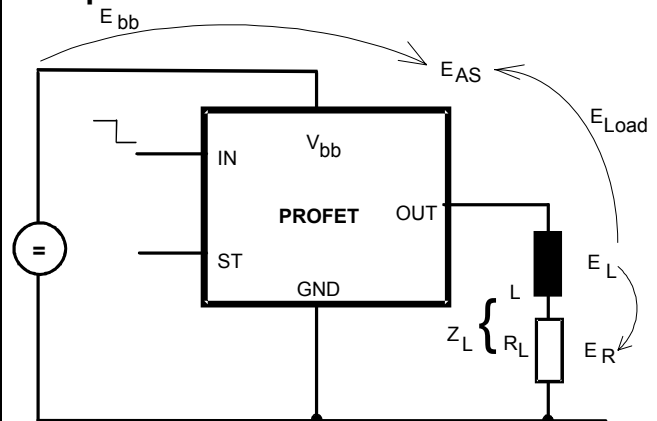
Any kind of load. If $V_{GND} > V_{IN} - V_{IN(T+)}$ device stays off
Due to $V_{GND} > 0$, no V_{ST} = low signal available.

V_{bb} disconnect with energized inductive load


Normal load current can be handled by the PROFET itself.

V_{bb} disconnect with charged external inductive load


If other external inductive loads L are connected to the PROFET, additional elements like D are necessary.

Inductive Load switch-off energy dissipation


Energy stored in load inductance:

$$E_L = \frac{1}{2} \cdot L \cdot I_L^2$$

While demagnetizing load inductance, the energy dissipated in PROFET is

$$E_{AS} = E_{bb} + E_L - E_R = \int V_{ON(CL)} \cdot i_L(t) dt,$$

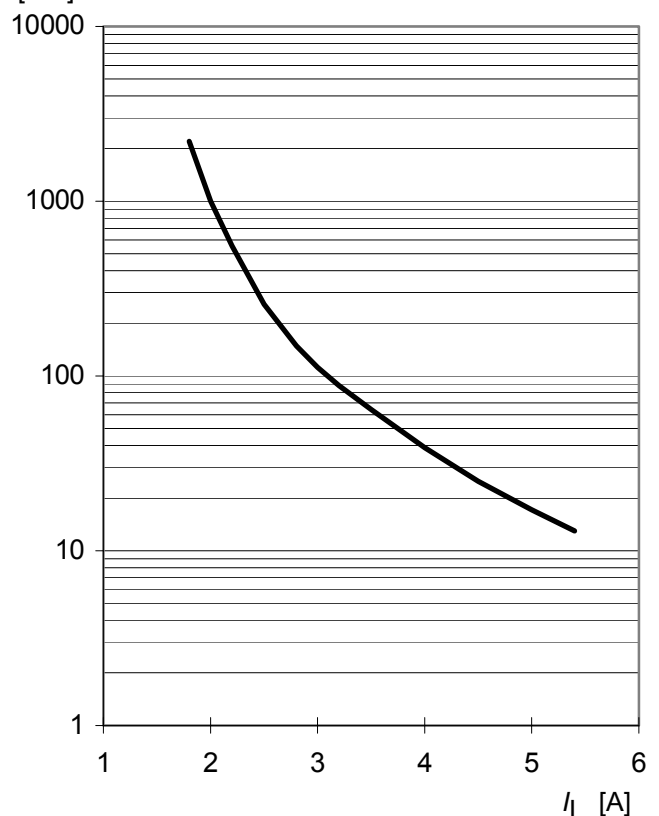
with an approximate solution for $R_L > 0 \Omega$:

$$E_{AS} = \frac{I_L \cdot L}{2 \cdot R_L} \cdot (V_{bb} + |V_{OUT(CL)}|) \cdot \ln \left(1 + \frac{I_L \cdot R_L}{|V_{OUT(CL)}|} \right)$$

Maximum allowable load inductance for a single switch off

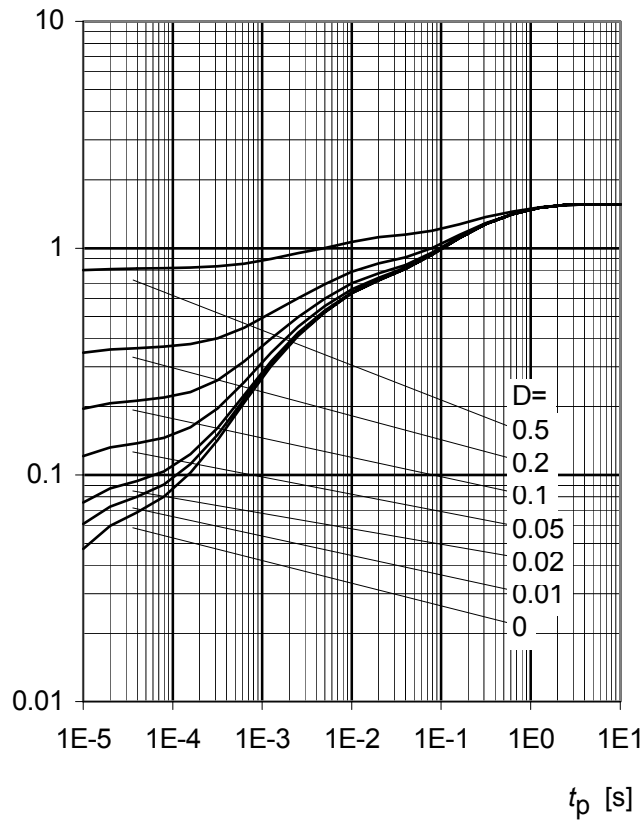
$L = f(I_L)$; $T_{j,start} = 150^\circ\text{C}$, $T_C = 150^\circ\text{C}$ const.,
 $V_{bb} = 12\text{ V}$, $R_L = 0 \Omega$

L [mH]



Typ. transient thermal impedance chip case

$$Z_{thJC} = f(t_p, D), D = t_p / T$$

 $Z_{thJC} [K/W]$


Options Overview

High-side switch, Input protection, ESD protection, load dump and reverse battery protection with 150 Ω in GND connection, protection against loss of ground

Type	ITS410E2
Logic version	E
Overtemperature protection with hysteresis $T_j > 150\text{ }^{\circ}\text{C}$, latch function ^{14),15)} $T_j > 150\text{ }^{\circ}\text{C}$, with auto-restart on cooling	X
Short circuit to GND protection switches off when $V_{ON} > 3.5\text{ V typ.}$ and $V_{bb} > 7\text{ V typ.}$ ¹⁴⁾ (when first turned on after approx. 150 μs) switches off when $V_{ON} > 8.5\text{ V typ.}$ ¹⁴⁾ (when first turned on after approx. 150 μs) Achieved through overtemperature protection	X
Open load detection in OFF-state with sensing current 30 $\mu\text{A typ.}$ in ON-state with sensing voltage drop across power transistor	X
Undervoltage shutdown with auto restart	X
Overvoltage shutdown with auto restart ¹⁶⁾	X
Status feedback for overtemperature short circuit to GND short to V_{bb} open load undervoltage overvoltage	X X - ¹⁷⁾ X - -
Status output type CMOS Open drain	X
Output negative voltage transient limit (fast inductive load switch off) to $V_{bb} - V_{ON(CL)}$	X
Load current limit high level (can handle loads with high inrush currents) low level (better protection of application)	X
Protection against loss of GND	X

¹⁴⁾ Latch except when $V_{bb} - V_{OUT} < V_{ON(SC)}$ after shutdown. In most cases $V_{OUT} = 0\text{ V}$ after shutdown ($V_{OUT} \neq 0\text{ V}$ only if forced externally). So the device remains latched unless $V_{bb} < V_{ON(SC)}$ (see page 4). No latch between turn on and $t_{d(SC)}$.

¹⁵⁾ With latch function. Reseted by a) Input low, b) Undervoltage

¹⁶⁾ No auto restart after overvoltage in case of short circuit

¹⁷⁾ Low resistance short V_{bb} to output may be detected in ON-state by the no-load-detection

Timing diagrams

Figure 1a: V_{bb} turn on:

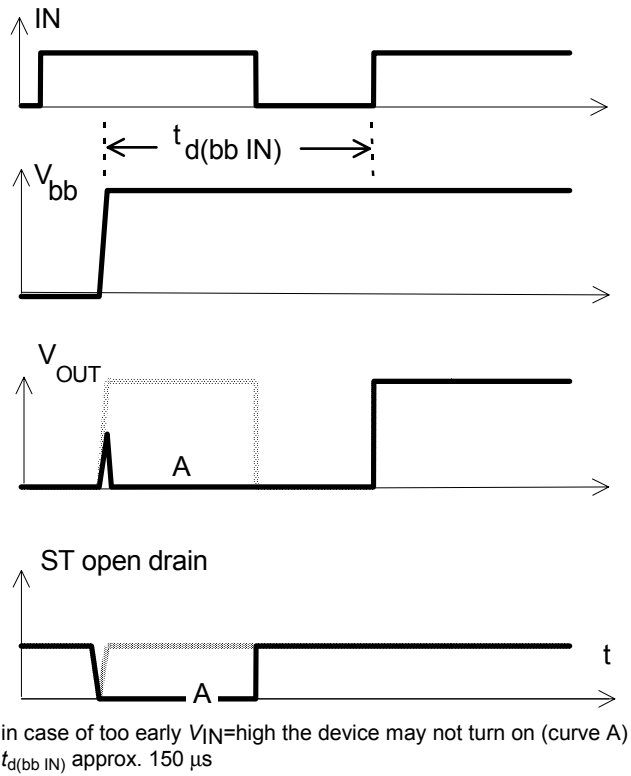


Figure 2a: Switching a lamp,

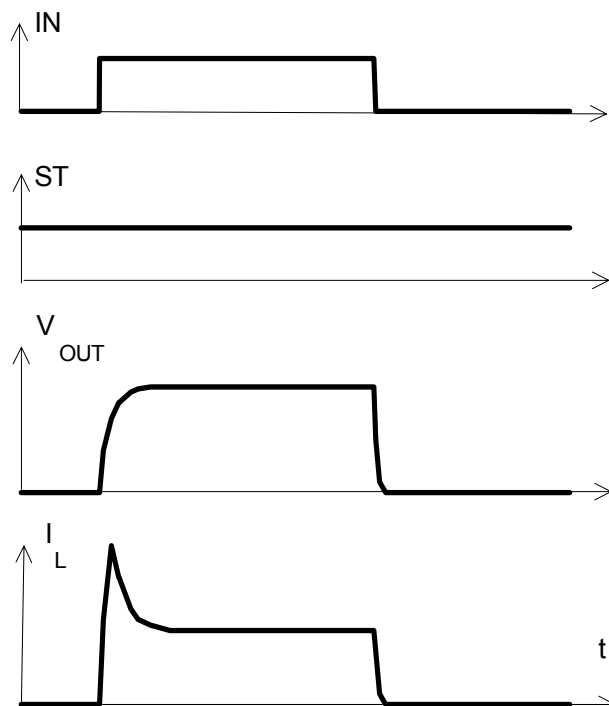
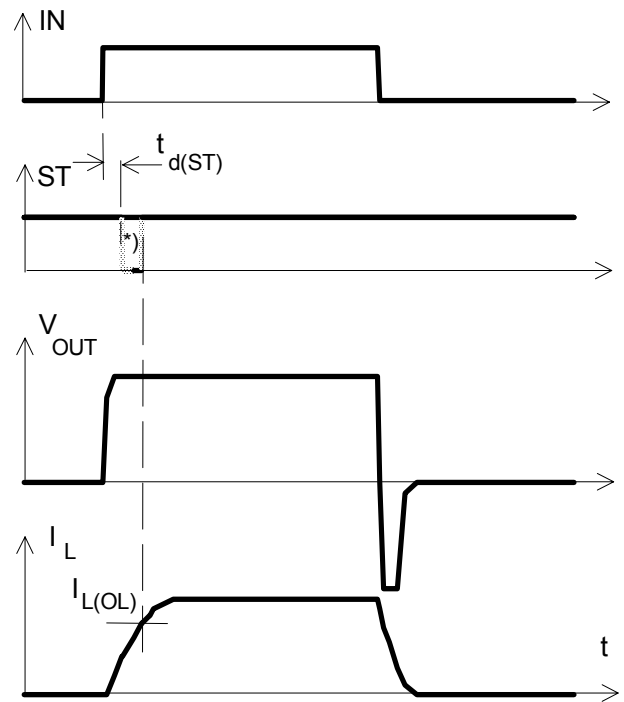
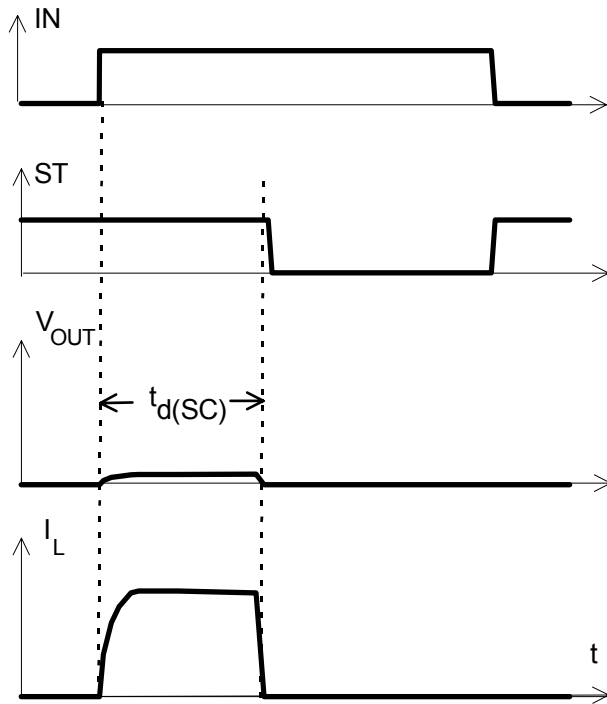


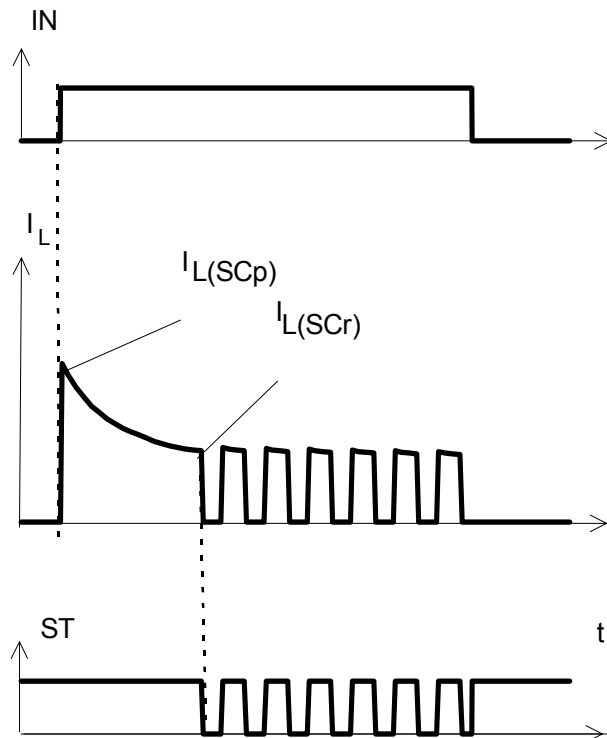
Figure 2b: Switching an inductive load



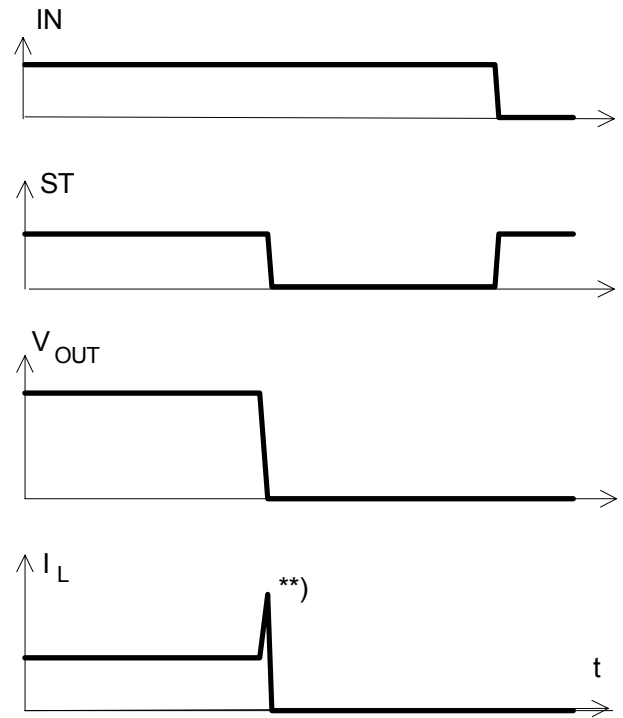
*) if the time constant of load is too large, open-load-status may occur

Figure 3a: Turn on into short circuit,


$t_{d(SC)}$ approx. -- μs if $V_{bb} - V_{OUT} > 8.5 V$ typ.

Figure 3b: Turn on into overload,


Heating up may require several seconds,
 $V_{bb} - V_{OUT} < 8.5 V$ typ.

Figure 3c: Short circuit while on:


** current peak approx. 20 μs

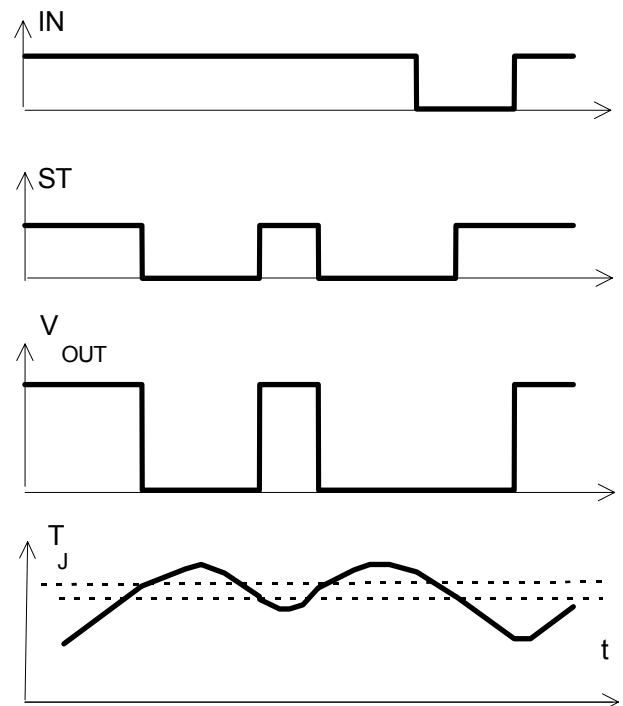
**Figure 4a: Overtemperature:
Reset if $T_j < T_{jt}$**


Figure 5a: Open load: detection in ON-state, turn on/off to open load

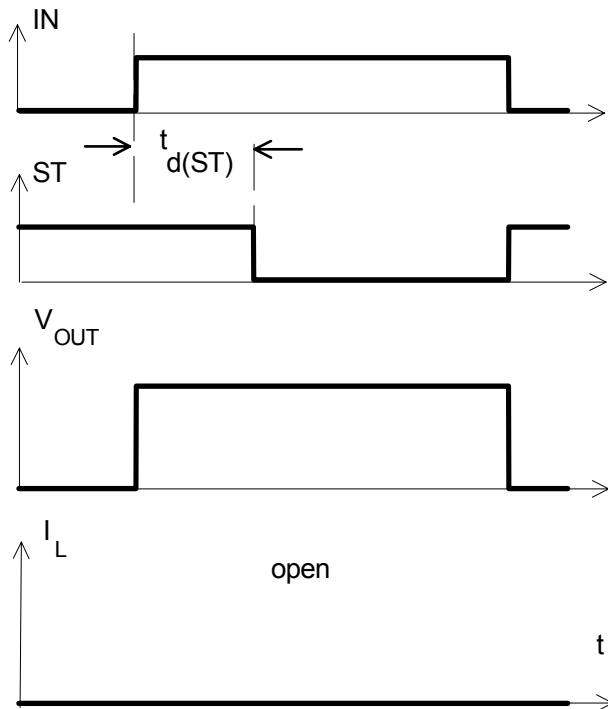


Figure 5b: Open load: detection in ON-state, open load occurs in on-state

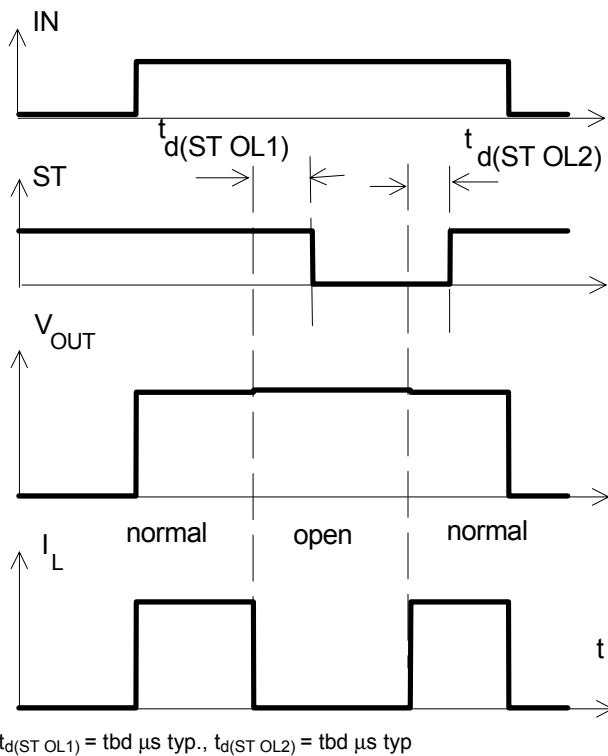


Figure 6a: Undervoltage:

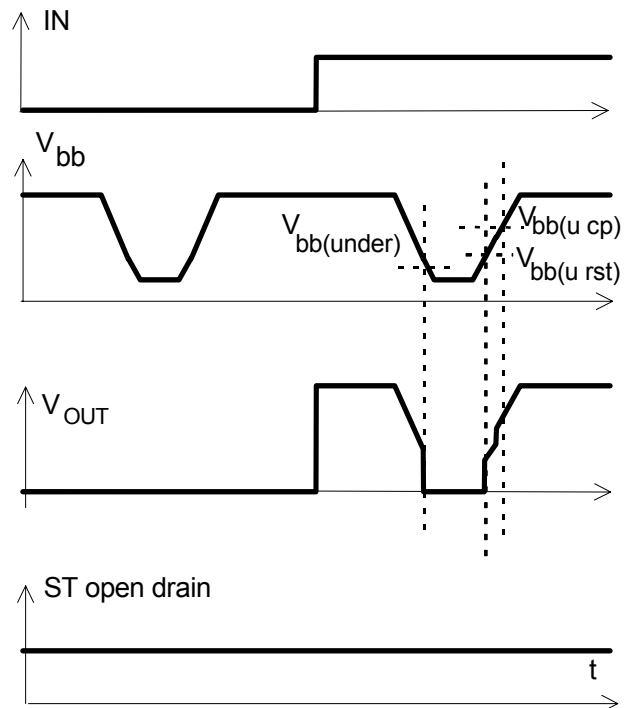


Figure 6b: Undervoltage restart of charge pump

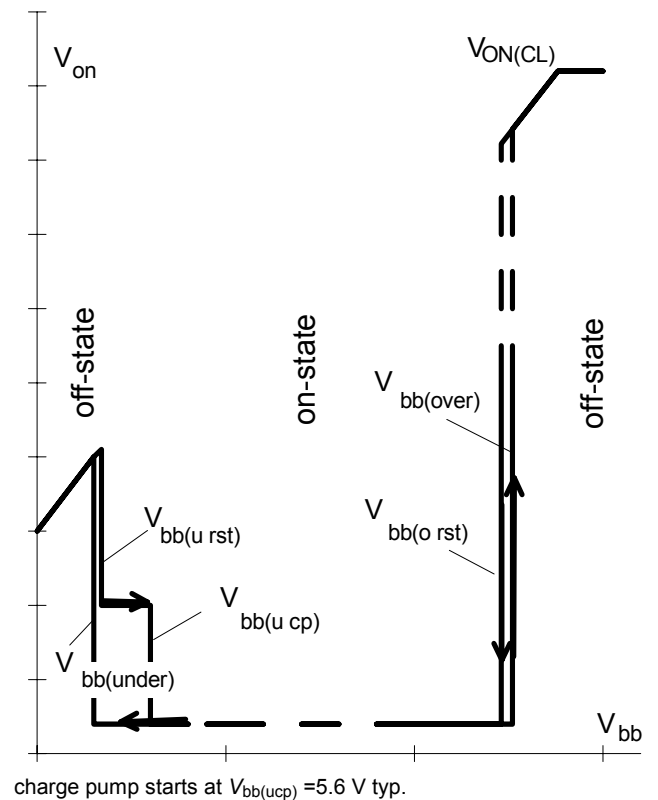
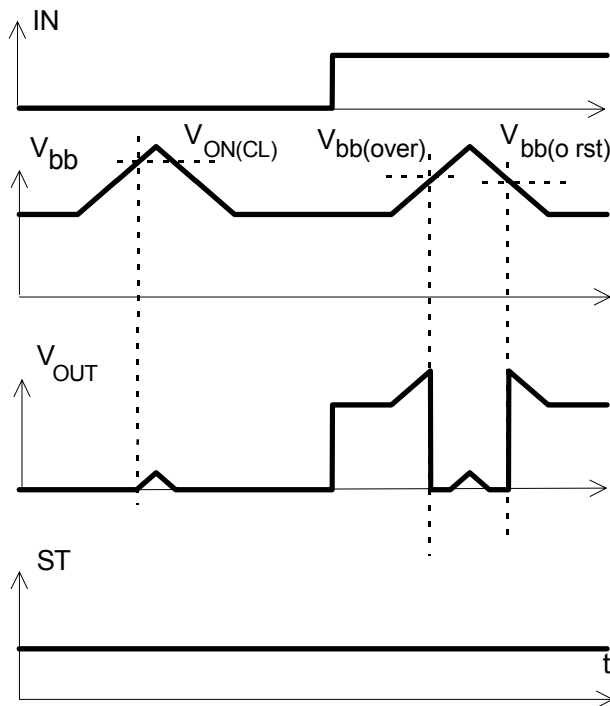
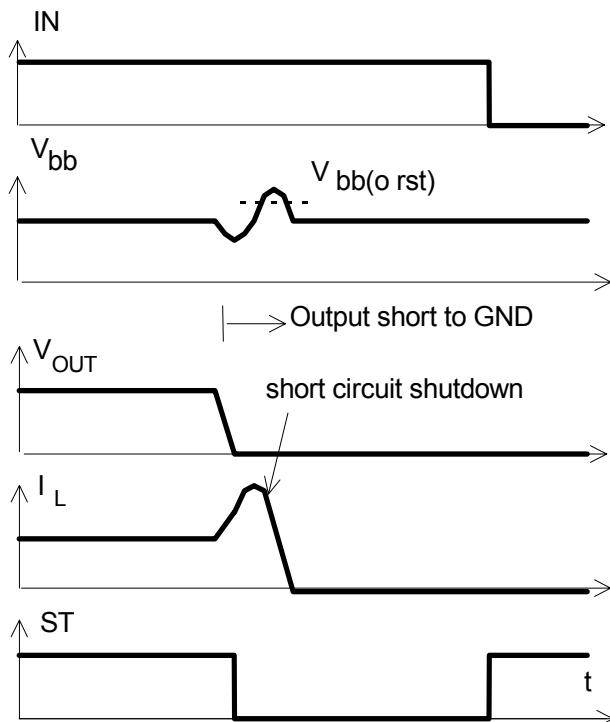


Figure 7a: Overvoltage:

Figure 9a: Overvoltage at short circuit shutdown:


Overvoltage due to power line inductance. No overvoltage auto-restart of PROFET after short circuit shutdown.

Package and Ordering Code

All dimensions in mm

Standard PG-TO220AB/5 Ordering code

ITS 410 E2		SP000221219
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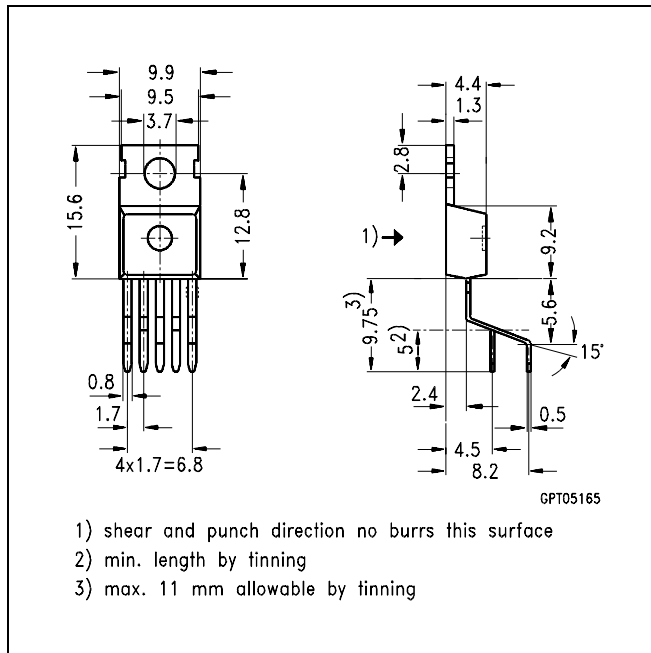
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PG-TO220AB/5, Option E3043 Ordering code

ITS 410 E2 E3043		SP000221227
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